# NSN 5961-01-123-1245

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-123-1245 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.085 inches and 0.130 inches **Function For Which Designed:** Voltage reference Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Quality assurance level txv **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 11.7 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 7.50 milliamperes all primaries horsepower metric and 45.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset

## **Maximum Operating Tempurature Per Measurement Point:**

175.0 degrees celsius junction

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

2 uninsulated wire lead

### **Specification Data:**

81349-mil-s-19500/157 government specification

Shelf Life:

N/a

**Unit Of Measure:** 

Demilitarization:

No

Fiig:

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